DATA SHEET

mos integrated circuit μ PD6124A, 6600A

4-BIT SINGLE-CHIP MICROCONTROLLER FOR REMOTE CONTROL TRANSMISSION

DESCRIPTION

NEC

★ The μPD6124A and 6600A are 4-bit single-chip microcontrollers for infrared remote controllers for TVs, VCRs, stereos, cassette decks, air conditions, etc.

These microcontrollers consist of ROM, RAM, a 4-bit parallel-processing ALU, a programmable timer, key input/ output ports, and transmit output ports. Functioning is controlled by a program.

A one-time PROM, model μ PD61P24, to which a program can be written only once is also available. This one-time PROM is ideal for evaluation of programs running in a μ PD6124A or 6600A, and for small-scale production of such systems.

FEATURES

- Transmitter for programmable infrared remote controller
- 19 types of instructions
- Instruction execution time: 17.6 μs (with 455-kHz ceramic resonator)
- Program memory (ROM) capacity
 - μ PD6124A: 1002 \times 10 bits
 - μ PD6600A: 512 \times 10 bits
- Data memory (RAM) capacity: 32×5 bits
- 9-bit programmable timer: 1 channel
- I/O pins (Ki/o): 8 pins
- Input pins (KI): 4 pins
- Serial input pins (S-IN): 1 pin

- Transmission-in-progress indication pin (S-OUT): 1 pin
- Transmit carrier frequency (REM) fosc/12, fosc/8
- Standby operation (HALT/STOP mode)
- Low power consumption
- Current consumption in STOP mode (T_A = 25°C)
- Low-voltage operation
 μPD6124A: V_{DD} = 2.2 to 5.5 V
 μPD6600A: V_{DD} = 2.2 to 3.6 V

Caution To use the NEC transmission format, ask NEC to supply the custom code. Do not use R₀ when using a register as an operand of the branch instruction.

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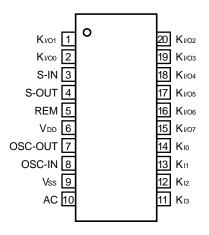
The information in this document is subject to change without notice.

ORDERING INFORMATION

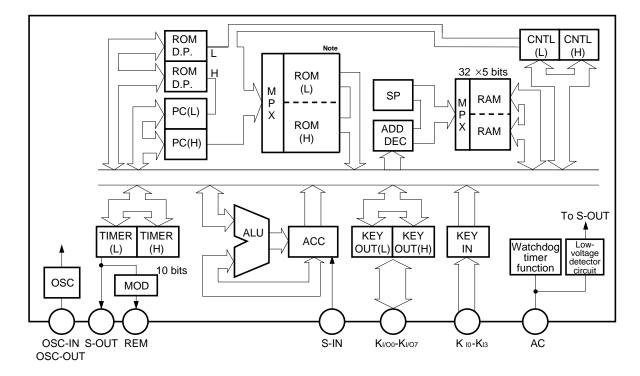
Part Number	Package
μPD6124ACS-XXX	20-pin plastic shrink DIP (300 mil)
μ PD6124AGS-XXX	20-pin plastic SOP (300 mil)
μ PD6600ACS-XXX	20-pin plastic shrink DIP (300 mil)
μ PD6600AGS-XXX	20-pin plastic SOP (300 mil)

Remark XXX indicates ROM code suffix.

PIN CONFIGURATION (TOP VIEW)



BLOCK DIAGRAM



Note ROM capacity depends on the products.

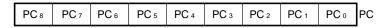
DIFFERENCES AMONG PRODUCTS

Item Product Name	μPD6124A	μPD6600A
ROM Capacity	1002×10 bits (Mark ROM)	512×10 bits (Mask ROM)
RAM Capacity	32×5 bits	
I/O Pins	8 (K1/00-K1/07)	
S-IN Pins	Provided	
Current Consumption	2 μΑ	
(fosc = STOP) (MAX.)		
S-IN High Level Input	30 µA	
Current (MAX.)		
Transmit Carrier Frequency	fosc/12, fosc/8	
Low-voltage Detector	Provided	
(Reset) Circuit		
Supply Current	V _{DD} = 2.2 to 5.5 V	V _{DD} = 2.2 to 3.6 V
Package	• 20-pin plastic SOP (300 mil)	
	• 20-pin plastic shrink DIP (300 mil)	

The program counter (PC) is a binary counter, which holds the address information for the program memory.

Figure 1-1. Program Counter Organization

(a) μPD6600A



(b) μPD6124A

PC 9 PC 8 PC 7 PC 6 PC 5	PC 4 PC 3	PC 2	PC 1	PC 0	PC
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Normally, the program counter contents are automatically incremented each time an instruction is executed, according to the number of instruction bytes.

When executing a jump instruction (JMP0, JC, JF), the program counter indicates the jump destination.

Immediate data or the data memory contents are loaded to all or some bits of the PC.

When executing the call instruction (CALL0), the PC contents are incremented (+1) and saved into the stack memory. Then, a value needed for each jump instruction will be loaded.

When executing the return instruction (RET), the stack memory contents are double incremented (+2) and loaded into the PC.

When "all clear" is input or on reset, the PC contents are cleared to "000H".

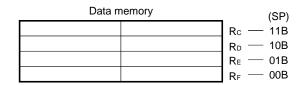
2. STACK POINTER (SP) 2 BITS

This 2-bit register holds the start address information for the stack area. The stack area is shared with the data memory.

The SP contents are incremented, when the call instruction (CALL0) is executed. They are decremented, when the return instruction (RET) is executed.

The stack pointer is cleared to "00B" after reset or "all clear" is input, and indicates the highest address FH for the data memory as the stack area.

The figure below shows the relationship for the stack pointer and the data memory area.



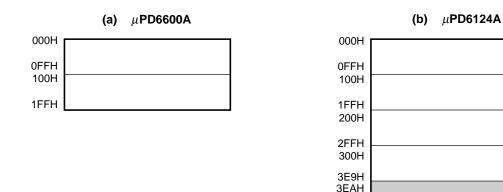
If the stack pointer overflows or underflows, it is determined that the CPU overflows, and the PC internal reset signal will be generated.

Test program

area

The program memory (ROM) is configured in 10 bits steps. It is addressed by the program counter. Program and table data are stored in the program memory.

Figure 3-1. Program Memory Map



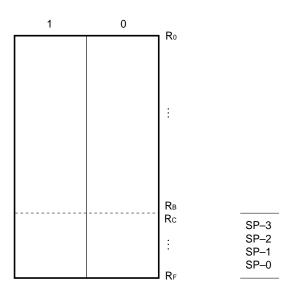
4. DATA MEMORY (RAM) 32 WORDS \times 5 BITS

The data memory is a RAM of 32 words \times 5 bits. The data memory stores processing data. In some cases, the data memory is processed in 8-bit units. R₀ may be used as the data pointer for the ROM.

3FFH

After power application, the RAM will be undefined. The RAM retains the previous data on reset.

Figure 4-1. Data Memory Organization



Caution Avoid using the RAM areas R_D, R_E, and R_F in a CALL routine as much as possible because these areas are also used as stack memory areas (to prevent program hang-up in case the value of the SP is destroyed due to some reason such as noise).

When using these RAM areas as general-purpose RAM areas, be sure to include stack pointer checking in the main routine.

5. DATA POINTER (R₀)

Ro (R10, R00) for the data memory can serve as the data pointer for the ROM.

R₀ specifies the low-order 8 bits in the ROM address. The high-order 2 bits in the ROM address are specified by the control register.

Table referencing for ROM data can be easily executed by calling the ROM contents by setting the ROM address to the data pointer.

On reset or "all clear" is input, it becomes undefined.

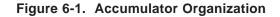


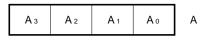


Note μ PD6600A: AD₉ = 0

6. ACCUMULATOR (A) 4 BITS

The accumulator (A) is a 4-bit register. The accumulator plays a major role in each operation. On reset or "all clear" is input, it becomes undefined.





7. ARITHMETIC LOGIC UNIT (ALU) 4 BITS

The arithmetic logic unit (ALU) is a 4-bit operation circuit, and executes simple operations, such as arithmetic operations.

8. FLAGS

(1) Status flag

When the status for each pin is checked by the STTS instruction, if the condition coincides with the condition specified by the STTS instruction, the status flag (F) is set (to 1).

On reset or "all clear" is input, it becomes undefined.

(2) Carry flag

When the INC (increment) instruction or the RL (rotate left) instruction is executed, if a carry is generated from the MSB for the accumulator, the carry flag (C) is set (to 1).

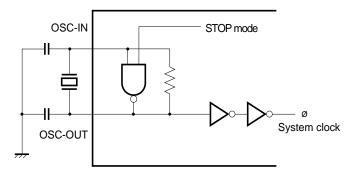
The carry flag (C) is also set (to 1), if the contents for the accumulator are "FH", when the SCAF instruction is executed.

On reset or "all clear" is input, it becomes undefined.

9. SYSTEM CLOCK GENERATOR

The system clock generator consists of a resonator, which uses a ceramic resonator (400kHz to 500kHz).

Figure 9-1. System Clock Generator



In the STOP mode (oscillation stop HALT instruction), the oscillator in the system clock generator stops its operation, and the system clock ϕ is stopped.

10. TIMER

The timer block determines the transmission output pattern. The timer consists of 10 bits, of which 9 bits serve as the 9-bit down counter and the remaining 1 bit serves as the 1-bit latch, which determines the carrier output validity.

The 9-bit down counter is decremented (-1) every 8/fosc(s) in synchronization with the machine cycle, after starting down count operation. Down counting stops after all of the 9 bits become 0. When down counting is stopped, the signal indicating that the timer operation has stopped, is output. If the CPU is at standby (HALT TIMER) for the timer operation completion, the standby (HALT) condition is released and the next instruction will be executed. If the next instruction again sets the value of the down counter, down counting continues without any error (the carrier output of the REM pin is not affected).

Set the down count time according to the following calculation; (set value (HEX) + 1) \times 8/fosc. Setting the value to the timer is done by the timer manipulation instruction.

When the down counter is operating, the remote control transmission carrier can be output to the REM pin. Whether or not to output the carrier can be selected by the MSB for the timer register block. Set "1", when outputting the carrier, or "0", when not outputting the carrier.

If all the down counter bits become "0", when outputting the carrier, the carrier output will be stopped. When not outputting the carrier, the REM pin output will become low level.

A signal in synchronization with the REM output is output to the S-OUT pin. However, the waveform for the S-OUT pin is low, when the carrier is being output to the REM pin, or it is high, when the carrier is not being output to the REM pin.

If the HALT instruction, which initiates the oscillation stop mode, is executed when the down counter is operating, the oscillation stop mode is initiated after down counting is stopped (after 0).

Timer operation STOP/RUN is controlled by the control register (P1). (Refer to **13. CONTROL REGISTER (P1)**.) At reset (all clear) time, the REM pin goes low and S-OUT pin goes high. All 10 bits of the timer are cleared to 000H.

Cautions 1. Because the timer clock is not synchronized with the carrier output, the pulse width may be shortened at the beginning and end of the carrier output.

2. Reset caused by the low-voltage detector circuit causes the S-OUT pin to output low level.

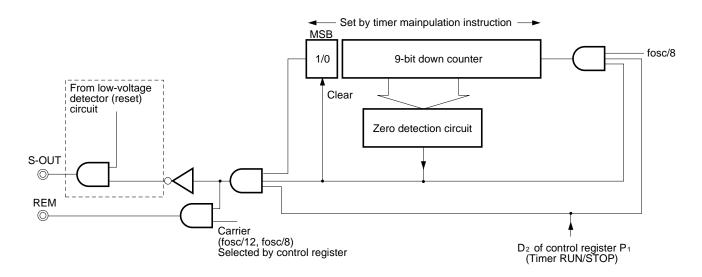


Figure 10-1. Timer Block Organization

11. PIN FUNCTIONS

11.1 Ki/o PIN (Po)

This is the 8-bit I/O pin for key-scan output. When the control register (P1) is set for the input port, the port can be used as an 8-bit input pin. When the port is set for the input mode, all of these pins are pulled down to the Vss level inside the LSI.

★ At reset (all cleared), the value of I/O mode and output latch becomes undefined.

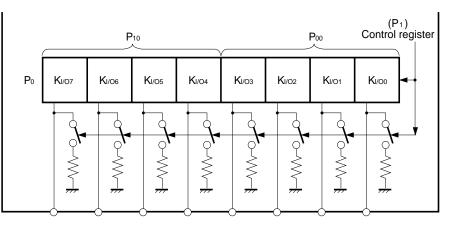
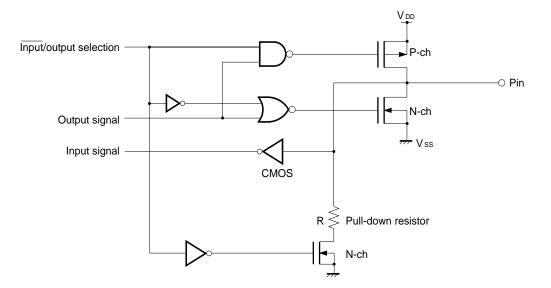


Figure 11-1. K_{I/0} Pin Organization

11.2 KI/O PULL-DOWN RESISTOR CONFIGURATION



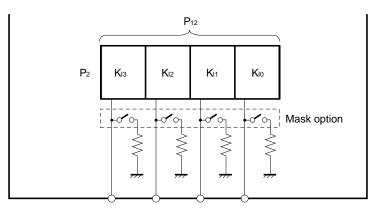
When $K_{I\!O}$ is set to the input mode, pull-down resistor R is turned on.

11.3 KI PIN (P12)

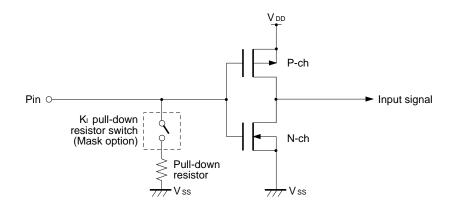
NEC

This is the 4-bit pin for key input. All of these pins can be pulled down to the Vss level by mask option.

Figure 11-2. K Pin Organization



11.4 KI PULL-DOWN RESISTOR CONFIGURATION



When the pull-down resistor switch is turned on (set 1) by the mask option, pull-down resistor R is turned on.

Caution When using the pin as the key switch, turn on the pull-down resistor switch by the mask option.

11.5 S-OUT PIN

By going low whenever the carrier frequency is output from the REM pin, the S-OUT pin indicates that communication is in progress.

★ The S-OUT pin is CMOS output. The S-OUT pin goes high on reset.

11.6 S-IN PIN (Do BIT OF P1)

To input serial data, use the S-IN pin. When control register (P1) is set to serial input mode, the S-IN pin is connected as an input to the LSB of the accumulator; the S-IN pin can be pulled down to the Vss level by a mask option from within the LSI. In this state, if the rotate-left accumulator instruction (RL A) is executed, the data on the S-IN pin is copied to the LSB of the accumulator.

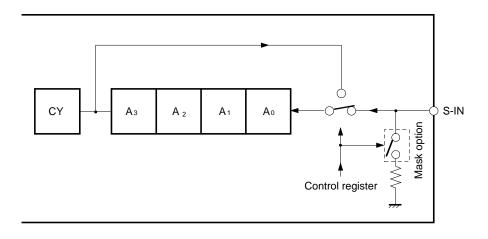
If the control register is released from serial input mode, the S-IN pin goes into a high-impedance state, but no through current flows internally.

When the RL A instruction is executed, the MSB is copied to the LSB.

★ At reset (all cleared), the S-IN pin goes into a high-impedance state.

Caution The μ PD6123 is not provided with an S-IN pin.





12. PORT REGISTER (Px)

 $K_{I\!/\!O},\,K_I,$ and the control register are handled as port registers.

The table below shows the relations between the port registers and pins.

Table 12-1. Relations between Port Registers and Pins

Pin	Input	Mode	Output	Mode	On Depart	
Name	Read	Write	Read	Write	On Reset	
Ki/o	Pin status	Output latch	Pin status Output latch		Undefined [input mode, output latch]	
Kı	Pin status	-	-	-	Input mode	
S-IN	Pin status is read l	by RL A instruction	when Do of P1 regi	ster = 1.	High impedance (Do of P1 register = 0)	

P1×(H)	P ₀ × (L)	_
К <i>и</i> от-4 Р 10	К иоз-о Р 00	P٥
Control register (H)	Control register (L)	P۱
K 13-0 P 12	 P ₀₂	₽₂

13. CONTROL REGISTER (P1)

The control register contains of 10 bits. The controllable items are shown in Table 13-1.

Table 13-1. Control Register (P1) (1/2)

(a) μPD6124A

Bit		D۹	D 8	D 7	D 6	D 5	D 4	D 3	D 2	D 1	D 0
Nam	e	Test	mode	_	HALT	D.P. AD₃	D.P. ADଃ	MOD	Timer	K i/o	RLAcc A₀ ←
Set	0	-		NOP	AD9=0	AD8=0	fosc/8	STOP	IN	A ₃	
Value	1	De	Be sure to set 0.		OSC STOP	AD9=1	AD ₈ =1	fosc/12	RUN	OUT	S-IN

D1 Specifies the status of Ki/o, as follows:

0: input mode, 1: output mode

- D₂ Specifies the status of the timer, as follows:
 - 0: Count stop, 1: Count execution
- D₃ Specifies the carrier frequency output from the REM pin.

0: fosc/8, 1: fosc/12

D4, D5..... Specify the high-order 2 bits of the ROM data pointer.

D6 Determines what happen to the oscillation circuit when the HALT instruction is executed.

- 0: Oscillation does not stop
- 1: Oscillation stops (STOP mode)
- D7 Be sure to set this bit to 0.
- D₈, D₉..... These bits specify test modes. Be sure to set them to 0.

Remark $D_0 = D_8 = D_9 = 0$ on reset, and the other bits are undefined.

Table 13-1. Control Register (P1) (2/2)

(b) μ**PD6600A**

Bit		D 9	D 8	D 7	D 6	D 5	D 4	Dз	D 2	D 1	D٥
Nam	e	Test	mode	-	HALT	D.P. AD₃	D.P. ADଃ	MOD	Timer	K i/o	RLAcc A₀ ←
Set	0	Pr	e sure to set	0	NOP	Be sure to	AD ₈ =0	fosc/8	STOP	IN	Аз

Do Specifies data to be input to Ao when the accumulator is shifted to the left.

D1 Specifies the status of KI/o, as follows:

0: input mode, 1: output mode

D2 Specifies the status of the timer, as follows:

0: Count stop, 1: Count execution

- D_3 Specifies the carrier frequency output from the REM pin.
 - 0: fosc/8, 1: fosc/12
- D4 Specify the MSB of the ROM data pointer.
- D_5 Be sure to reset them to 0.
- D6 Determines what happen to the oscillation circuit when the HALT instruction is executed.
 - 0: Oscillation does not stop
 - 1: Oscillation stops (STOP mode)
- D7 Be sure to set this bit to 0.
- $\mathsf{D}_8,\,\mathsf{D}_9$ These bits specify test modes. Be sure to set them to 0.

Remark $D_0 = D_8 = D_9 = 0$ on reset, and the other bits are undefined.

^{0:} A3, 1:S-IN

14. STANDBY FUNCTION (HALT INSTRUCTION)

The μ PD6600A is provided with the standby mode (HALT instruction), in order to reduce the power consumption, when not executing the program. Clock oscillation can be stopped in the standby mode (STOP mode).

In the standby mode, the program execution stops. However, the contents of the internal registers and the data memory are all retained.

14.1 STOP MODE (OSCILLATION STOP HALT INSTRUCTION)

In the STOP mode, the operation of the system clock generator (ceramic resonator oscillation circuit) stops. Therefore, operations requiring the system clock will stop.

If the HALT instruction is executed during timer operation, the program counter stops. The oscillation stop mode will be initiated, after the timer count down operation is completed.

14.2 HALT MODE (OSCILLATION CONTINUE HALT INSTRUCTION)

The CPU stops its operation, until the HALT release condition is satisfied. The system clock operation continues in this mode.

14.3 STANDBY RELEASE CONDITIONS

- (1) S-IN input
- (2) Ki/o input
- (3) Ki input
- (4) Timer count down operation completion

Remark Either high level or low level can be specified for setting a release condition by input.

D3	D2	D1	D٥	Releasing Condition	Remarks
	0	0	0	S-IN	When $RL \leftarrow A_3$ is selected, the standby mode is always released.
0/1	0	0	1	K 1/0	Valid only in the IN mode.
	0	1	0	Kı	
0	0	1	1	Timer	Released when 0.

→ Releasing condition: "0"…Low level detection

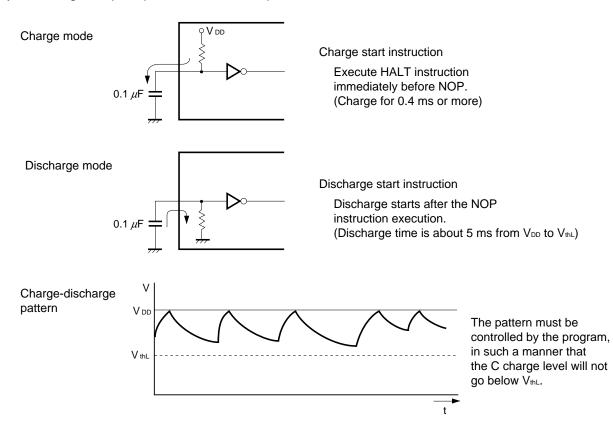
"0"...Low level detection "1"...High level detection

15. AC PIN (ALL CLEAR PIN)

Internal part of the CPU including the program counter can be reset by setting the AC pin to the low level.

WATCHDOG TIMER FUNCTION

A power-on reset function and a CR watchdog timer function, that can be controlled by program, can be realized by connecting a 0.1 μ F capacitor across the AC pin and the Vss.

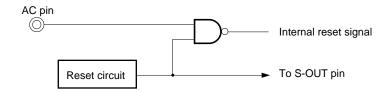


Caution When the watchdog timer function is not used, switch to charging mode by executing a NOP instruction immediately before a HALT instruction at the beginning of the program. (Be sure to connect the capacitor.)

16. LOW-VOLTAGE DETECTOR (RESET) CIRCUIT

The μ PD6124A and 6600A are internally provided with the low-voltage detector (reset) circuit, in order to prevent program hang-up.

When VDD goes down to 1 V or below, an internal reset signal is generated. In the reset condition, a low level is output to the S-OUT pin.



Caution The low-voltage detector circuit starts operating at a voltage ranging from 1 to 2.2 V. Hence, if the supply voltage is 2 V or lower, the program counter may hang up before the low-voltage detector circuit operates.

17. MASK OPTIONS (PLA DATA)

The following items can be selected by mask option selection:

- Provide/not provide Ki, S-IN pin pull-down resistor
- Carrier duty selection (1/2, 1/3) at fosc/12
- Hang-up detection specification

Mask option data should be registered at the object code end.

BIT ASSIGNMENT BY SWITCH SELECTION

s		MSB	MSB							
Address	Corresponding Portion	7	6	5	4	3	2	1	0	
		'	0	5	-	5	2	I	0	
0	Kı pull-down resistor ^{Note}	Кıз	K12	Kıı	Кю			0		
1	Duty S-IN	0	0	0	Duty selection	0	0	S-IN pull-down resistor	0	
2	Hang-up detection	Ki/o ALL	HALT S-IN	HALT Ki/o	HALT Kı			0		

Note The setting (bit) positions differ from the μ PD6125A and 6126A.

SWITCH FOR DATA

- Pull-down resistor
 When 0 ··· Not provided (OFF)
 When 1 ··· Provided (ON)
- Modulation duty (at fosc/12)
 When 0 ··· 1/2 duty
 When 1 ··· 1/3 duty
- (3) Hang-up detection
 - <1> Ki/o ALL

Caution

If the switch for hang-up detection K_{1/0} ALL is set to ON (1) by mask option, the system is reset if, in oscillation HALT (STOP) mode, the K_{1/0} pin is in input mode, or if at least one of the K_{1/0} pins is low (AC pin discharge mode).

When 0 ··· No reset function (OFF) When 1 ··· Reset function (ON)



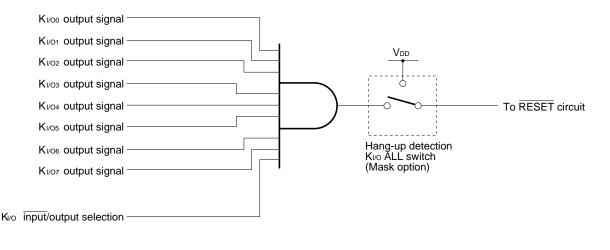
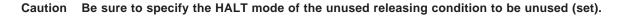


Figure 17-1. Hang-up Detection K_{I/0} ALL Configuration Diagram

To use a pin as a key source of a key matrix, be sure to set the switch to ON by mask option.

<2> HALT releasing condition specification (S-IN, K_I/o, K_I) If the condition specified by mask option to be unused is satisfied in the HALT mode, the system is reset. When 0 … Used When 1 … Unused



18. PROGRAM DEVELOPMENT TOOLS

To develop programs for the μ PD6124A and 6600A, an assembler and an emulator for the μ PD612X series are available from I.C. Corp. For details, contact IC Corp.

IC Corporation 6th Barnet Gotanda Bldg. 1-9-5 Higashi-Gotanda, Shinagawa-ku Tel. 03-3447-3793 Fax. 03-3440-5606

 Caution To develop the programs for the μPD6124A and 6600A, use the μPD6124 because the μPD6124A and 6600A are not available as the target devices for assembly and emulation. The upper limit of ROM addresses is different in the μPD6124A/6600A and μPD6124. Make sure that the program does not exceed 512 steps by checking the end address of the assembly listing after assembling the program. The mask option of the μPD6124A/6600A is the same as that of the μPD6124.

19. ORDERING ROM CODE

<1> To generate the data required for ordering a mask ROM, after assembling the program, convert the HEX file to a ROM file by using the PROM utility program "UPDPROM".

Caution When using "UPDPROM" select "27256" for PROM TYPE.

<2> Confirm that the instruction ROM code data is stored in addresses 0 through 7D3H (3FFH in µPD6600A) of the PROM.

Also confirm that the mask option ROM code data are stored in addresses 7FF0H through 7FF2H.

20. INSTRUCTION SET

ACCUMULATOR MANIPULATION INSTRUCTIONS

	Rr	_	R 10	R11	R 12		R1F	R 00	R 01		ROF
ANL	A, Rr		D00	D01	D02		D0F	D20	D21		D2F
ANL	A, @R₀H	D10									
ANL	A, @R₀L	D30									
ANL	A, #data	D31									
ORL	A, Rr		E00	E01	E02		E0F	E20	E21		E2F
ORL	A, @R₀H	E10									
ORL	A, @R₀L	E30									
ORL	A, #data	E31									
XRL	A, Rr		A00	A01	A02		A0F	A20	A21		A2F
XRL	A, @R₀H	A10									
XRL	A, @R₀L	A30									
XRL	A, #data	A31									
INC	А	A13									
RL	А	F13				<u> </u>				<u> </u>	

INPUT/OUTPUT INSTRUCTIONS

PP	P10	P11	P12	P00	P01	P ₀₂
IN A, P _P	F18	F19	F1A	F38	F39	F3A
OUT PP, A	218	219	21A	238	239	23A
ANL A, P _P	D18	D19	D1A	D38	D39	D3A
ORL A, P _P	E18	E19	E1A	E38	E39	E3A
XRL A, P _P	A18	A19	A1Z	A38	A39	A3A

PP	P ₀	P1	P ₂
OUT P∘ #data	318	319	31A

P_{1P} and P_{0P} operate in pair format

DATA TRANSFER INSTRUCTIONS

Rr		R 10	R 11	R 12	R1F	R00	R 01	ROF
MOV A, Rr		F00	F01	F02	F0F	F20	F21	F2F
MOV A, @R₀H	F10							
MOV A, @R₀H	F30							
MOV A, #data	F31							
MOV Rr , A		200	201	202	20F	220	221	22F

Rr	R₀	R₁	R2	RF
MOV Rr, #data	300	301	302	30F
MOV Rr, @Ro	320	321	322	32F

R1r and R0r operate in pair format

BRANCH INSTRUCTIONS

		Rr	_	R₀	R1	R2	RF	←Pair register
	JMP0	addr	411					
*	JMP0	Rr ^{Note}	-	-	401	402	40F	
	JC	addr	611					
	JC	Rr ^{Note}	-	-	601	602	60F	
	JNC	addr	631			622		
	JNC	Rr ^{Note}	-	-	621		62F	
	JF	addr	711					
	JF	Rr ^{Note}	-	-	701	702	70F	
	JNF	addr	731					
	JNF	Rr ^{Note}	-	-	721	722	 72F	

***** Note r = 1 through F

r = 0 canot be used.

SUBROUTINE INSTRUCTIONS

CALL0 addr	312	411
RET	412	

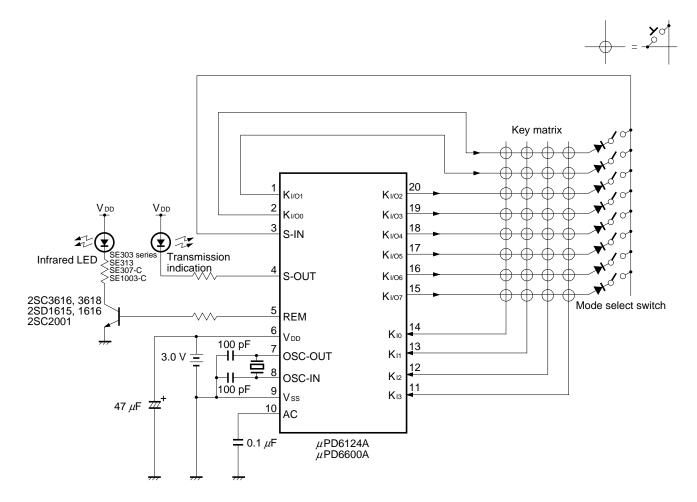
TIMER/COUNTER MANIPULATION INSTRUCTIONS

Tt	T 0-1	T1	Τo
MOV A, T _t	-	F1F	F3F
MOV T _t , A		21F	23F
MOV T, #data	31F		
MOV T, @R₀	33F		

OTHER INSTRUCTIONS

		R00	R ₀₁	R 02	Rof
HALT #data	111				
STTS Ror		120	121	122	 12F
STTS #data	131				
SCAF	D13				
NOP	000				

21. APPLICATION CIRCUIT EXAMPLE



Caution The ceramic resonator start up capacitor value must be determined, by taking the voltage level and the oscillation start up characteristics for the ceramic resonator into consideration.

22

22. ELECTRICAL SPECIFICATIONS

(1) µPD6124A Electrical Specifications

ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

Parameter	Symbol	mbol Ratings	
Supply Voltage	Vdd	-0.3 to +7.0	V
Input Voltage	Vin	-0.3 to VDD + 0.3	V
Operating Ambient Temperature	ТА	-20 to +75	°C
Storage Temperature	Tstg	-40 to +125	°C

Caution Even if one of the parameters exceeds its absolute maximum rating even momentarily, the quality of the product may be degraded. The absolute maximum rating therefore specifies the upper or lower limit of the value at which the product can be used without physical damages. Be sure to use the product(s) within the ratings.

RECOMMENDED OPERATING RANGE (TA = -20 to +75 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vdd	2.2		5.5	V
Oscillation Frequency	fosc	400		500	kHz

DC CHARACTERISTICS (VDD = 3.0 V, fosc = 455 kHz, TA = 25 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vdd		2.2		5.5	V
Current Consumption 1	IDD1	fosc = 455 kHz		0.3	1.0	mA
Current Consumption 2	IDD2	fosc = STOP			2.0	μA
REM High Level Output Current	Іон1	Vo = 1.0 V	-5	-8		mA
REM Low Level Output Current	IOL1	Vo = 0.3 V	0.5	1.5	2.5	mA
S-OUT High Level Output Current	Іон2	Vo = 2.7 V	-0.3	-1.0	-2.0	mA
S-OUT Low Level Output Current	IOL2	Vo = 0.3 V	1	1.5		mA
Kı High Level Input Current	IIH1	VI = 3.0 V	10		30	μA
KI High Level Input Current	Іін1'	VI = 3.0 V, without pull-down resistor			0.2	μA
KI Low Level Input Current	lı∟1	VI = 0 V			-0.2	μA
Ki/o High Level Input Current	Іін2	VI = 3.0 V	10		30	μA
Ki/o High Level Input Current	Іін2'	VI = 3.0 V, without pull-down resistor			0.2	μA
Ki/o Low Level Input Current	IIL2	VI = 0 V			-0.2	μA
Ki/o High Level Output Current	Іонз	V0 = 2.5 V	-1.5	-2.0	-4.0	mA
Ki/o Low Level Output Current	IOL3	Vo = 2.1 V	25	50	100	μA
S-IN High Level Input Current	Іінз	VI = 3.0 V	6		30	μA
S-IN High Level Input Current	Іінз'	VI = 3.0 V, without pull-down resistor			0.2	μA
S-IN Low Level Input Current	lil3	VI = 0 V			-0.2	μA
Kı High Level Input Voltage	VIH1		2.1		3.0	V
Ki Low Level Input Voltage	VIL1	VI = 3.0 V	0		0.9	V
Ki/o High Level Input Voltage	VIH2		1.3		3.0	V
Ki/o Low Level Input Voltage	VIL2		0		0.4	V
S-IN High Level Input Voltage	Іінз		1.1		3.0	V
S-IN Low Level Input Voltage	lil3		0		0.4	V
AC Pull-Up Resistor	R1	VI = 0 V	0.3		3.0	kΩ
AC Pull-Down Resistor	R2	VI = 2.7 V	150		1500	kΩ
AC High Level Input Voltage	VIH4		1.8		3.0	V
AC Low Level Input Voltage	VIL4		0		1.2	V

(2) *µ*PD6600A Electrical Specifications

ABSOLUTE MAXIMUM RATINGS (T_A = 25 $^{\circ}$ C)

Parameter	Symbol	Ratings	Unit
Supply Voltage	Vdd	-0.3 to +7.0	V
Input Voltage	Vin	-0.3 to VDD + 0.3	V
Operating Ambient Temperature	Та	-20 to +75	°C
Storage Temperature	Tstg	-40 to +125	°C

Caution Even if one of the parameters exceeds its absolute maximum rating even momentarily, the quality of the product may be degraded. The absolute maximum rating therefore specifies the upper or lower limit of the value at which the product can be used without physical damages. Be sure to use the product(s) within the ratings.

RECOMMENDED OPERATING RANGE (TA = -20 to +75 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vdd	2.2		3.6	V
Oscillation Frequency	fosc	400		500	kHz

DC CHARACTERISTICS (VDD = 3.0 V, fosc = 455 kHz, TA = 25 $^{\circ}\text{C}$)

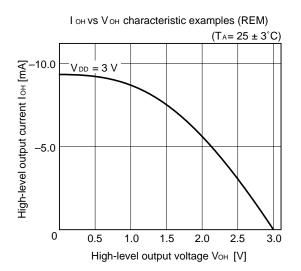
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vdd		2.2		3.6	V
Current Consumption 1	IDD1	fosc = 455 kHz		0.3	1.0	mA
Current Consumption 2	IDD2	fosc = STOP			2.0	μA
REM High Level Output Current	Іон1	Vo = 1.0 V	-5	-8		mA
REM Low Level Output Current	IOL1	Vo = 0.3 V	0.5	1.5	2.5	mA
S-OUT High Level Output Current	Іон2	Vo = 2.7 V	-0.3	-1.0	-2.0	mA
S-OUT Low Level Output Current	IOL2	Vo = 0.3 V	1	1.5		mA
Kı High Level Input Current	IIH1	VI = 3.0 V	10		30	μA
Kı High Level Input Current	Іін1'	VI = 3.0 V, without pull-down resistor			0.2	μA
KI Low Level Input Current	lı∟1	VI = 0 V			-0.2	μA
Ki/o High Level Input Current	Іін2	VI = 3.0 V	10		30	μA
Ki/o High Level Input Current	Іін2'	VI = 3.0 V, without pull-down resistor			0.2	μA
Ki/o Low Level Input Current	IIL2	VI = 0 V			-0.2	μA
Ki/o High Level Output Current	Іонз	Vo = 2.5 V	-1.5	-2.0	-4.0	mA
Ki/o Low Level Output Current	IOL3	Vo = 2.1 V	25	50	100	μA
S-IN High Level Input Current	Іінз	VI = 3.0 V	6		30	μA
S-IN High Level Input Current	Іінз'	VI = 3.0 V, without pull-down resistor			0.2	μA
S-IN Low Level Input Current	lil3	VI = 0 V			-0.2	μA
Kı High Level Input Voltage	VIH1		2.1		3.0	V
Ki Low Level Input Voltage	VIL1	VI = 3.0 V	0		0.9	V
Ki/o High Level Input Voltage	VIH2		1.3		3.0	V
Ki/o Low Level Input Voltage	VIL2		0		0.4	V
S-IN High Level Input Voltage	Іінз		1.1		3.0	V
S-IN Low Level Input Voltage	lil3		0		0.4	V
AC Pull-Up Resistor	R1	VI = 0 V	0.3		3.0	kΩ
AC Pull-Down Resistor	R2	VI = 2.7 V	150	400	1500	kΩ
AC High Level Input Voltage	VIH4		1.8		3.0	V
AC Low Level Input Voltage	VIL4		0		1.2	V

RECOMMENDED CERAMIC RESONATOR

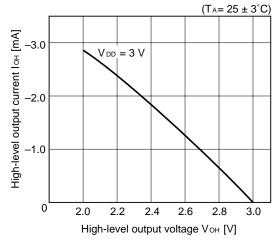
(Common in μ PD6124A and 6600A)

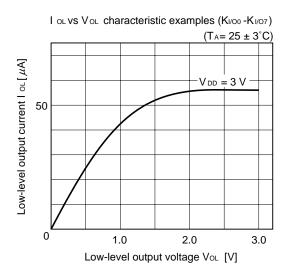
Manufacturan	Draduct	External Capacitance (pF)		Oscillation Voltage Range (V)		Describe
Manufacturer	Product	C1	C2	MIN.	MAX.	Remarks
Murata Mfg. Co., Ltd.	CSB375P	220	220	2.0	3.3	
	CSB400P	220	220	2.0	5.0	
	CSB455E	100	100	2.0	5.0	
	CSB480E	100	100	2.0	5.0	
	CSB500E	100	100	2.0	3.3	
Toko Ceramic Co., Ltd.	CRK400	100	100	2.0	6.0	
	CRK455	100	100	2.0	6.0	
	CRK500	100	100	2.0	6.0	

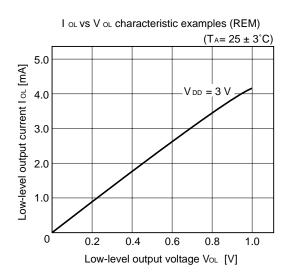
23. CHARACTERISTICS CURVE (REFERENCE VALUE) (Common in μ PD6124A and 6600A)



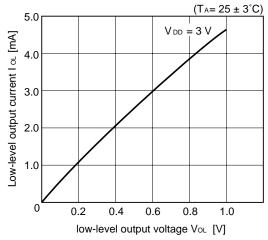
I онvs V он characteristic examples (S-OUT)



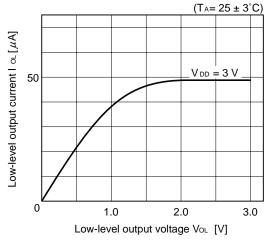


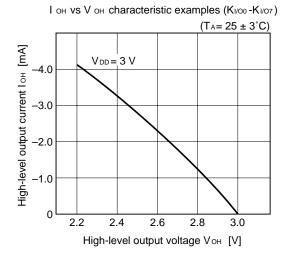








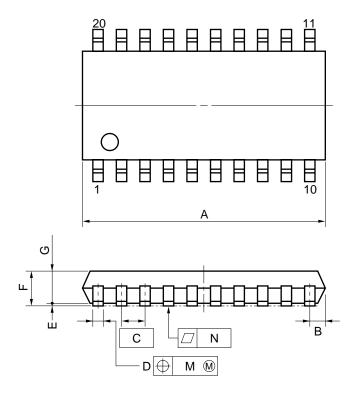




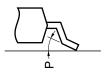
28

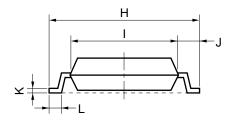
24. PACKAGE DRAWINGS

20 PIN PLASTIC SOP (300 mil)



detail of lead end





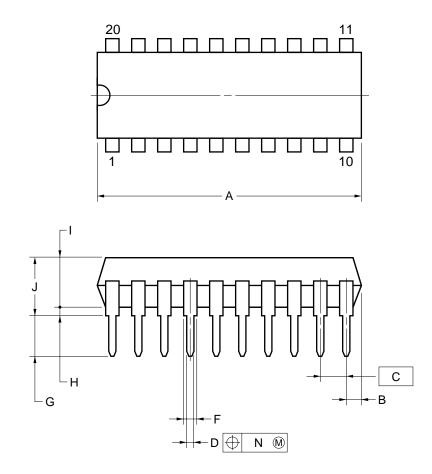
NOTE

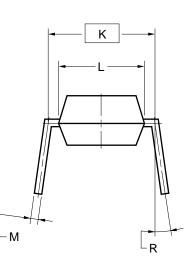
Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
А	13.00 MAX.	0.512 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
Н	7.7±0.3	0.303±0.012
<u> </u>	5.6	0.220
J	1.1	0.043
к	$0.20^{+0.10}_{-0.05}$	$0.008^{+0.004}_{-0.002}$
L	0.6±0.2	$0.024^{+0.008}_{-0.009}$
М	0.12	0.005
Ν	0.10	0.004
Р	3°+7° -3°	3°+7° -3°
	D20	CM 50 2000 C

P20GM-50-300B, C-4

20PIN PLASTIC SHRINK DIP (300 mil)





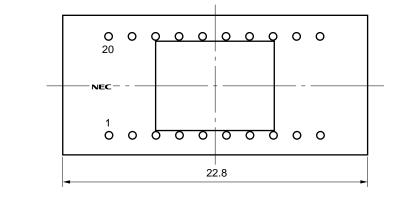
NOTES

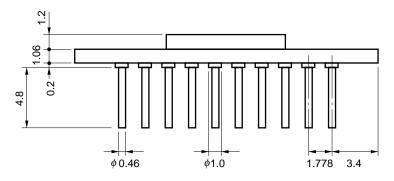
- 1) Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

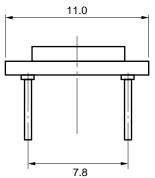
ITEM	MILLIMETERS	INCHES
A	19.57 MAX.	0.771 MAX.
В	1.78 MAX.	0.070 MAX.
С	1.778 (T.P.)	0.070 (T.P.)
D	0.50±0.10	$0.020^{+0.004}_{-0.005}$
F	0.85 MIN.	0.033 MIN.
G	3.2±0.3	0.126±0.012
Н	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
К	7.62 (T.P.)	0.300 (T.P.)
L	6.5	0.256
М	$0.25^{+0.10}_{-0.05}$	$0.010^{+0.004}_{-0.003}$
N	0.17	0.007
R	0~15°	0~15°
		P20C-70-300B-1

P20C-70-300B-1

20-PIN SHRINK DIP FOR ES (REFERENCE) (UNITS IN mm)







25. RECOMMENDED SOLDERING CONDITIONS

It is recommended that μ PD6124A and 6600A be soldered under the following conditions.

For details on the recommended soldering conditions, refer to Information Document "**Semiconductor Device Mounting Technology Manual**" (C10535E).

For other soldering methods and conditions, consult NEC.

Table 25-1. Soldering Conditions of Surface-Mount Type

★ μ PD6124AGS-XXX: 20-pin plastic SOP (300 mil)

µPD6600AGS-XXX: 20-pin plastic SOP (300 mil)

Soldering Method	Soldering Conditions	Symbol for Recommended Condition
Infrared Reflow	Package peak temperature: 230°C, time: 30 seconds max. (210°C min.), number of times: 1	IR30-00-1
VPS	Package peak temperature: 215°C, time: 40 seconds max. (200°C min.), number of times: 1	VP15-00-1
Wave Soldering	Soldering bath temperature: 260°C max., time: 10 seconds max., number of times: 1 Pre-heating temperature: 120°C max. (package surface temperature)	WS60-00-1
Partial Heating	Pin temperature: 300°C max., time: 3 seconds max. (per side)	_

Caution Do not use two or more soldering methods in combination (except the partial heating method).

*

Table 25-2. Soldering Conditions of Through-Hole Type

μPD6124ACS-XXX: 20-pin plastic shrink DIP (300 mil) μPD6600ACS-XXX: 20-pin plastic shrink DIP (300 mil)

Soldering Method Soldering Conditions	
Wave Soldering (Only for pin part)	Soldering bath temperature: 260°C max., time: 10 seconds max.
Partial Heating	Pin temperature: 300°C max., time: 30 seconds max.

Caution The wave soldering must be performed at the pin part only. Note that the solder must not be directly contacted to the package body.

APPENDIX μ PD612× SERIES PRODUCT LIST

\star

Part Number Item	μPD6124A	μΡD6600A	μPD61P24	μPD6125A	μPD6126A	
ROM capacity	1002 × 10 bits (mask ROM)	512×10 bits (mask ROM)	1002×10 bits (one-time PROM)	1002×10 bits (mask ROM)		
RAM capacity	32×5 bits					
I/O pin	8 pins (K _{1/00-7})			12 pins (K1/00-7, I/O00-03)	16 pins (K1/00-7, I/O00-03, I/O10-13)	
S-IN pin	Provided					
Current consumption (fosc = STOP) (MAX.)	2 μΑ		1 <i>µ</i> A			
S-IN high-level input current (MAX.)	30 μA 15		15 μA			
Transmission carrier frequency	fosc/12, fosc/8					
Low-voltage detection (reset) function	Provided		None			
Mask option	Provided		None (fixed)	Provided		
Supply voltage	V_{DD} = 2.0 to 5.5 V	V_{DD} = 2.2 to 3.6 V	V_{DD} = 2.2 to 5.5 V	$V_{DD} = 2.0$ to 6.0 V		
Package	 20-pin plastic SC 20-pin plastic shr 			 24-pin plastic SOP (300 mil) 24-pin plastic shrink DIP (300 mil) 	• 28-pin plastic SOP (375 mil)	

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

NEC

Regional Information

Some information contained in this document may vary from country to country. Before using any NEC product in your application, please contact the NEC office in your country to obtain a list of authorized representatives and distributors. They will verify:

- · Device availability
- · Ordering information
- Product release schedule
- · Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

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NEC Electronics Taiwan Ltd. Taipei, Taiwan Tel: 02-719-2377 Fax: 02-719-5951

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[MEMO]

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NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.

M4 96.5